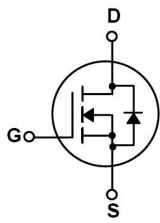


TO-263 N MOS N-CHANNEL MOSFET in a TO-263 Plastic Package.

Low $R_{DS(on)}$, low gate charge, low C_{rss} , fast switching.

Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products.

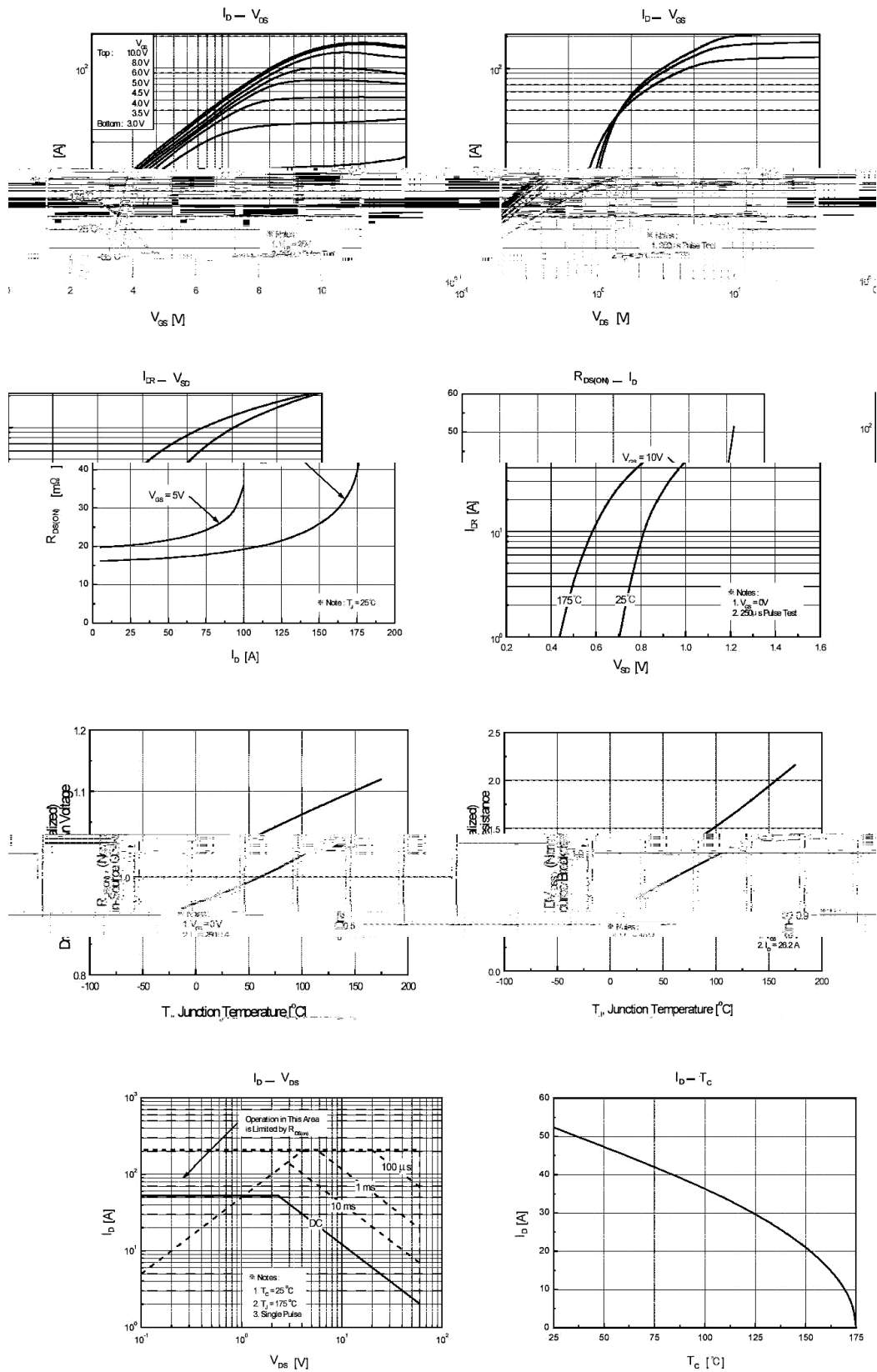


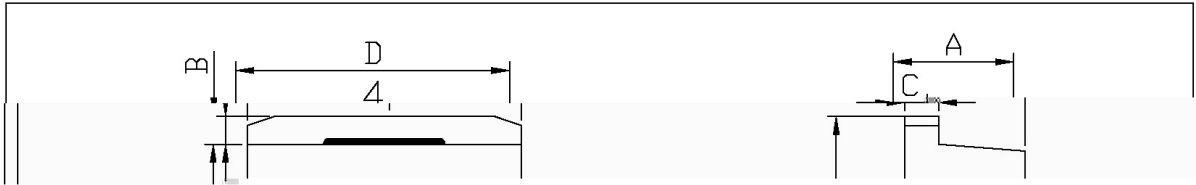
PIN1 G PIN 2,4 D PIN 3 S

See Marking Instructions

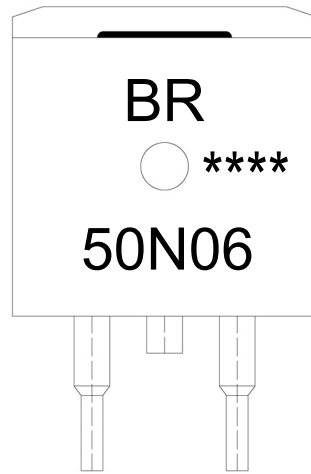
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DSS}	60	V
Drain Current		$I_D(T_c=25^\circ\text{C})$	50	A
Drain Current		$I_D(T_c=100^\circ\text{C})$	35.4	A
Drain Current - Pulsed		I_{DM}	200	A
Gate-Source Voltage		V_{GS}	± 20	V
Single Pulsed Avalanche Energy		E_{AS}	490	mJ
Repetitive Avalanche Energy		E_{AR}	12	mJ
Power Dissipation		$P_D(T_c=25^\circ\text{C})$	120	W
Junction Temperature Range		T_J	150	
Storage Temperature Range		T_{stg}	-55 ~ 150	
Junction to Ambient	$t \leq 10\text{s}$	$R_{\theta JA}$	13	/W
	Steady-State		60	
Junction to Case		$R_{\theta JC}$	1.6	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0\text{V}$ $I_D=250\mu\text{A}$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60\text{V}$ $V_{GS}=0\text{V}$			1.0	μA
		$V_{DS}=48\text{V}$ $T_C=150$			10	
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20\text{V}$ $V_{DS}=0\text{V}$			± 0.1	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu\text{A}$	2		4	V
Total Gate Charge	Q_g	$V_{DS}=48\text{V}$ $I_D=50\text{A}$ $V_{GS}=10\text{V}$		32	42	nC
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10\text{V}$ $I_D=25\text{A}$		0.018	0.022	Ω
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0\text{V}$ $I_S=50\text{A}$			1.5	V
Input Capacitance	C_{iss}	$V_{DS}=25\text{V}$ $V_{GS}=0\text{V}$ $f=1.0\text{MHz}$		1050	1365	pF
Output Capacitance	C_{oss}			460	600	pF
Reverse Transfer Capacitance	C_{rss}			70	90	pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=30\text{V}$ $I_D=25\text{A}$ $R_G=25\Omega$		20	50	ns
Turn-On Rise Time	t_r			100	210	ns
Turn-Off Delay Time	$t_{d(off)}$			80	170	ns
Turn-Off Fall Time	t_f			85	180	ns





単位: mm								
Symbol	Dimensions in Millimeters		Symbol	Dimensions in Millimeters				
	Min	Max		Min	Max			
A	4.30	4.70	E	9.00	9.40			
B	1.00	1.40	e1	2.34	2.74			
b	0.70	0.90	e2	4.88	5.28			
b1	1.15	1.35	L1	15.00	16.00			
b2	0.40	0.60	L2	2.24	2.44			
C	1.20	1.40	L3	1.20	1.40			
D	9.80	10.20						
T.0-263								



BR

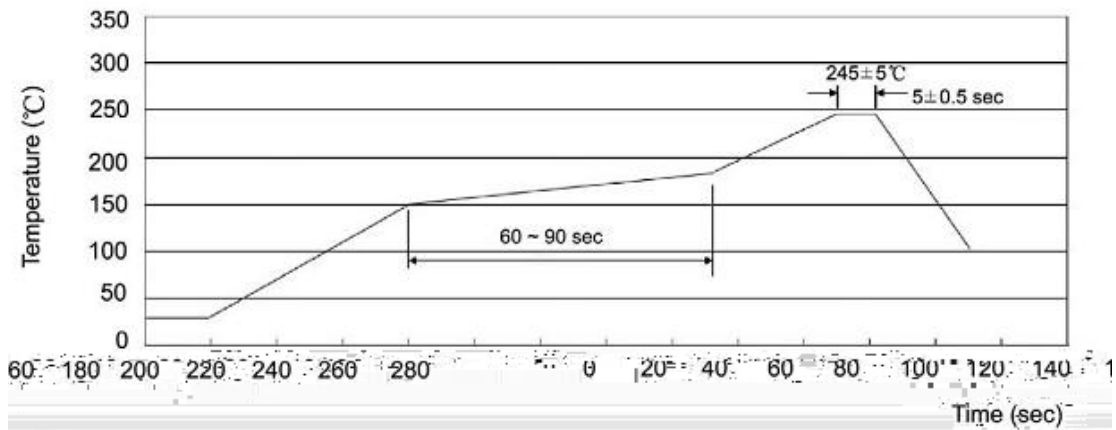
50N06

Note:

BR: Company Code

50N06: Product Type.

****: Lot No. Code, code change with Lot No.



Note:

1. Preheating: 150~180 °C, Time: 60~90sec.
2. Peak Temp.: 245±5 °C, Duration: 5±0.5sec.
3. Cooling Speed: 2~10 °C/sec.

260±5 °C, 10±1 sec, Temp.: 260±5 °C, Time: 10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
TO-263	800	1	800	5	4,000	13 × 24	360×360×50	385×257×392

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-263	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180